Vishay Semiconductors

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Hyperfast Rectifier, 75 A FRED Pt[®] G5



PRIMARY CHARACTERISTICS				
I _{F(AV)}	75 A			
V _R	600 V			
V _F at I _F at 125 °C	1.2 V			
t _{rr} (typ.)	32			
I _{FSM}	615			
T _J max.	175 °C			
Package	TO-247AD 2L			
Circuit configuration	Single			

LINKS TO ADDITIONAL RESOURCES



FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- · Polyimide passivation
- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminal:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Repetitive peak reverse voltage	V _{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 113 °C, D = 0.50	75		
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	615	A	
Repetitive peak forward current	I _{FRM}	T _C = 113 °C, D = 0.50, f = 20 kHz	150		
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C	

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	MBOL TEST CONDITIONS MIN. TYP. M		MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage	VF	I _F = 75 A	-	1.3	1.7	V
Forward voltage	۷F	I _F = 75 A, T _J = 125 °C	-	1.2	-	
Devenes la classe coment	I _R	$V_{R} = V_{R}$ rated	-	-	25	
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA
Junction capacitance	CT	V _R = 200 V	-	96	-	pF
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH

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1



COMPLIANT

HALOGEN

VS-E5PH7506LHN3



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	32	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	52	-	ns
		T _J = 125 °C		-	82	-	
Pool room ourrent		T _J = 25 °C	I _F = 50 A dI _F /dt = 1000 A/μs V _R = 400 V	-	24	-	A
Peak recovery current	I _{RRM}	T _J = 125 °C		-	51	-	
	Q _{rr}	T _J = 25 °C		-	805	-	nC
Reverse recovery charge		T _J = 125 °C		-	2515	-	
Boyeroo roooyery timo	+	T _J = 25 °C		-	57	-	20
Reverse recovery time	t _{rr}	T _J = 125 °C		-	90	-	ns
Deale recovery everyont		T _J = 25 °C	I _F = 75 A dI _F /dt = 1000 A/μs V _R = 400 V	-	28	-	A nC
Peak recovery current	IRRM	T _J = 125 °C		-	58	-	
Reverse recovery charge	0	T _J = 25 °C		-	969	-	
	Q _{rr}	T _J = 125 °C		-	3090	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.5	°C/W
Weight			-	5.5	-	g
			-	0.2	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Marking device		Case style TO-247AD 2L	E5PH7506LH			

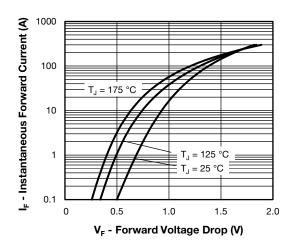


Fig. 1 - Forward Voltage Drop Characteristics

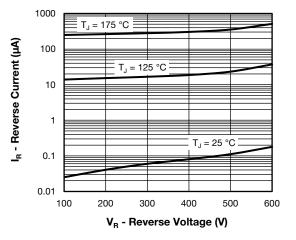


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

Document Number: 96819



VS-E5PH7506LHN3

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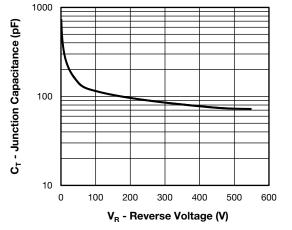


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

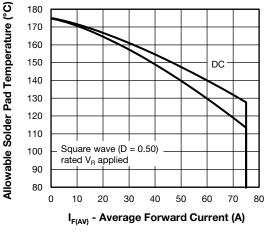


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

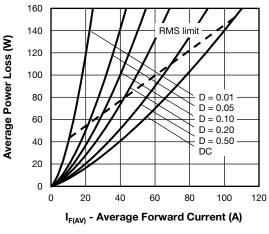


Fig. 5 - Forward Power Loss Characteristics

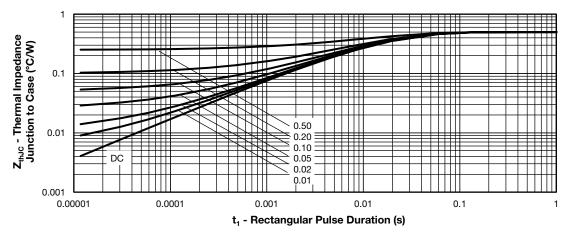


Fig. 6 - Transient Thermal Impedance, Junction to Case

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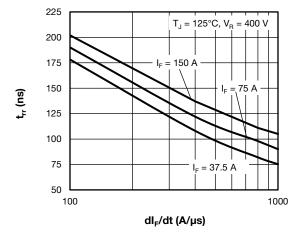


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

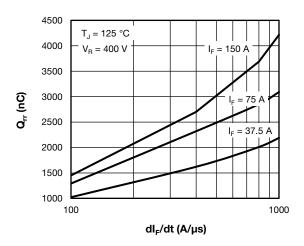


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

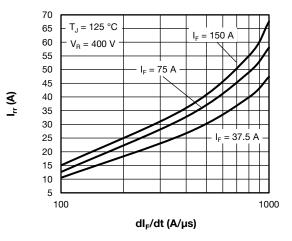
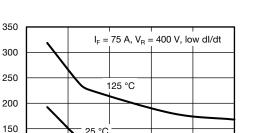
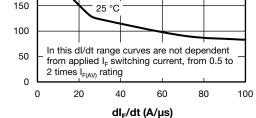


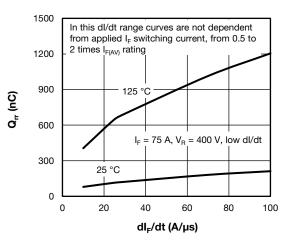
Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt





t_{rr} (ns)

Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt





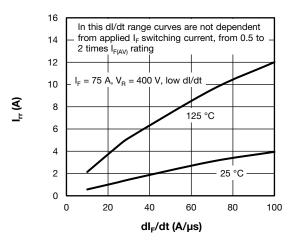


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

Revision: 17-Mar-2021

4

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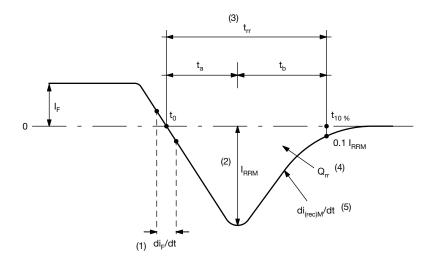


Fig. 13 - Reverse Recovery Waveform and Definitions

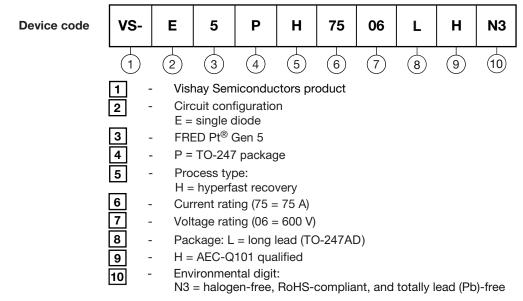
Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- $^{(2)}\ \ I_{RRM}$ peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~Q_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-E5PH7506LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95536			
Part marking information	www.vishay.com/doc?95648			

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